

P1.

$$(i) f(E) = \frac{1}{1 + e^{(E - E_f)/kT}}$$

$$(a) E - E_f = 0.5 kT$$

$$f(E) = \frac{1}{1 + e^{0.5}} = 0.3775$$

$$(b) E - E_f = 5 kT$$

$$f(E) = \frac{1}{1 + e^5} = 0.0067$$

(ii)

$$(a) N_D = \frac{n}{e^{(-E_c - E_f)/kT}}$$

$$E_f - E_c = kT \times \ln \left( \frac{N_D}{n} \right) = kT \cdot \ln \frac{1 \times 10^{15}}{1.5 \times 10^{10}} = 0.026 \times 6.5023 = 0.169 \text{ eV}$$

$$(b) E_f - E_c = kT \cdot \ln \left( \frac{5 \times 10^{14}}{1.5 \times 10^{10}} \right) = -0.2708 \text{ eV}$$

$$(c) np = n_i^2$$

$$n = 45 \times 10^5 \text{ cm}^{-3}$$

(iii) (a)

$$V_0 = V_T \cdot \ln \left( \frac{N_A N_D}{n_i^2} \right)$$

$$V_T = \frac{kT}{q} \approx 0.0259 \text{ V}$$

$$V_0 = 0.0259 \times \ln \left( \frac{1.0 \times 10^{13} \times 5 \times 10^{14}}{(1.5 \times 10^{10})^2} \right) = 0.438 \text{ V}$$

(b)  $W_{\text{dep}} = W_p + W_n$

$$\epsilon_s = 11.7 \times 8.85 \times 10^{-14}$$

$$= \sqrt{\frac{2\epsilon_s}{q} \left[ \frac{1}{N_A} + \frac{1}{N_D} \right] V_0}$$

$$= \sqrt{\frac{11.7 \times 10^{-14} \times 8.85}{1.6 \times 10^{-19}} \left[ \frac{1}{5 \times 10^{14}} + \frac{1}{10^{13}} \right] \times 0.438}$$

$$= 7.65 \times 10^{-4} \text{ cm}$$

$$\frac{W_p}{W_n} = \frac{N_D}{N_A} = \frac{1}{50}$$

$$W_p + W_n = 51 W_p = 7.65 \times 10^{-4} \text{ cm}$$

$$W_p = 1.49 \times 10^{-5} \text{ cm}$$

$$W_n = 7.46 \times 10^{-4} \text{ cm}$$

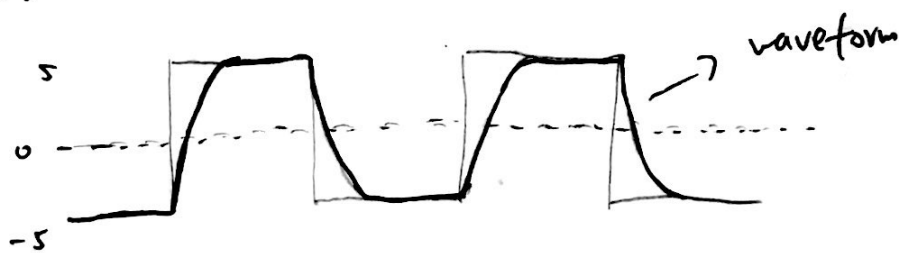


when the voltage reaches 5.7V, the top diode is on and higher voltage will not increase the value.

when the voltage is below -5.7, the bottom diode is on and -5.7V is the lowest that can be observed

$$-5.7 \leq \text{out} \leq 5.7$$

(b)



$$t_p = 0.69 RC = 0.69 \times 1000000 \times 1 \times 10^{-12} < \frac{1}{2} T$$

$$T = \frac{1}{100k}$$

$$(C) \quad C_j = \frac{dQ_j}{dV_d} = A_D \sqrt{\frac{2q\epsilon_s N_A \cdot N_D}{N_A + N_D}} (\phi_0 - V_d)^{-1/2}$$

$$AD = ~~12~~ 12 \mu m^2 = 12 \times 10^{-6} cm^2$$

$$\epsilon_s = 11.7 \times 8.85 \times 10^{-14} \quad q = 1.602 \times 10^{-19}$$

$$N_A = 10^{16}$$

$$N_D = 10^{17} \quad \phi_0 = 0.65 \quad ~~\phi_0~~$$

when  $V_{out} = 5.7$  . the top diode is on.

the bottom diode is off.

$$V_d \text{ across it is } ~~5.7 + 5 = 10.7~~ - 5.7 - 5 = -10.7$$

sub in all values.

$$C_j = 1.95 \times 10^{-13} f$$

P<sub>3</sub>. N:  $V_{GS} = V_G - V_S$   
 $= 5 - V_O$

$V_{DS} = V_D - V_S$   
 $= 5 - V_O$

P:  $V_{SG} = V_S - V_G = V_O - V_{in}$

$V_{SD} = V_S - V_D = V_O$

(a) when  $V_{in} = 0$  V

N:  $V_{DS} > V_{GS} - V_T \Rightarrow \text{Sat}$

P:  $V_{SD} > V_{SG} - V_T \Rightarrow \text{Sat.}$

$I_P = I_N$

$K_P (|V_{GS}| - |V_{TH}|)^2 = K_N (V_{GS} - V_{TH})^2$

$\frac{10}{10} \times \frac{20}{10} \times \frac{10}{20} (V_O - \cancel{V_{in}} - 1)^2 = (5 - V_O - 1)^2 \Rightarrow V_O = 2.5$

when  $V_{in} = 5$  V

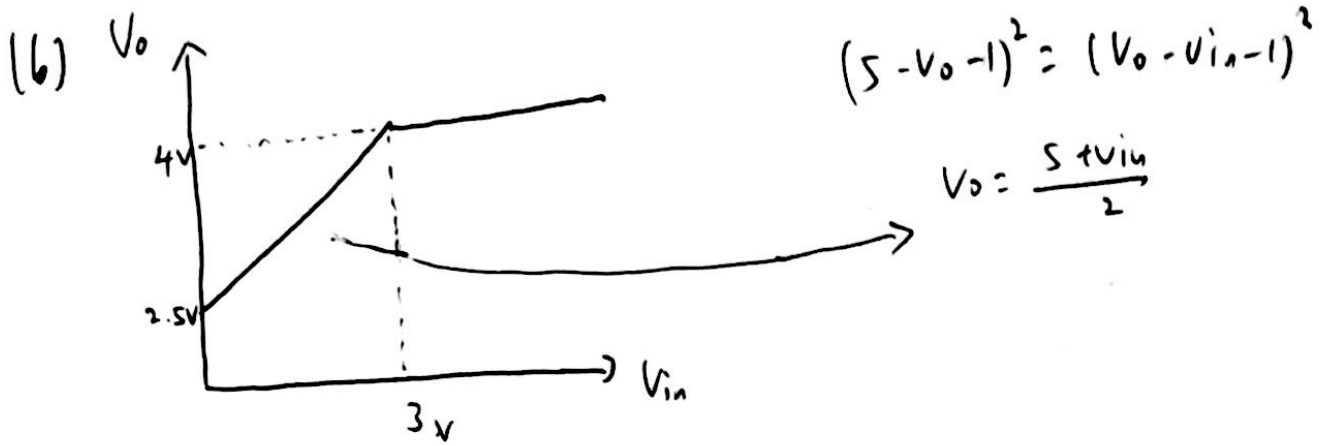
P: off

N: Sat

NMOS will be off as well if  $V_{GS} < V_{con}$

$5 - V_O < 1$

Therefore the maximum  $V_O$  is  $5 - V_{con} = 4$  V



(c) 
$$V_T = V_{T0} + \frac{\gamma (\sqrt{2|\phi_F| + V_{DS}} - \sqrt{2|\phi_F|})}{A}$$

both in sat.

$$5 - V_o - V_{T0} - A = V_o - V_{in} - A \quad (\text{no body effect for PMOS})$$

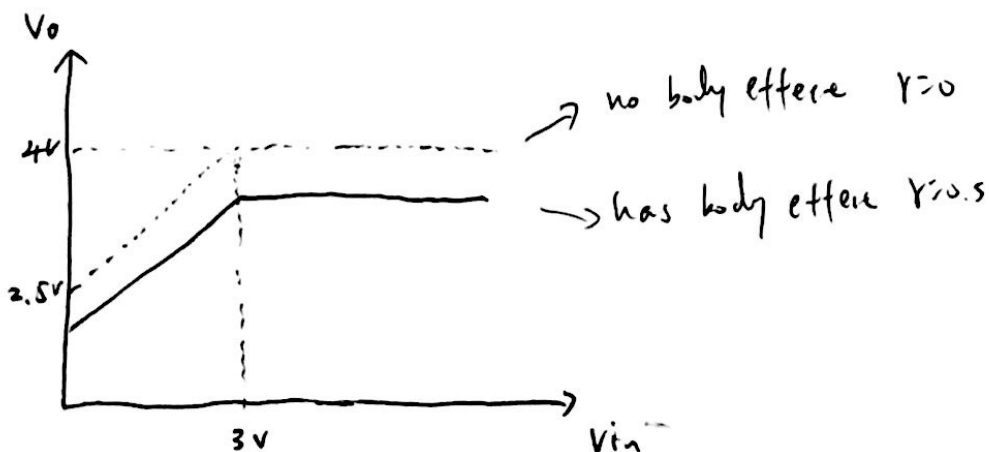
$$V_o = \frac{5 + V_{in}}{2} - \frac{A}{2} \quad V_o \text{ decrease}$$

when P is off.

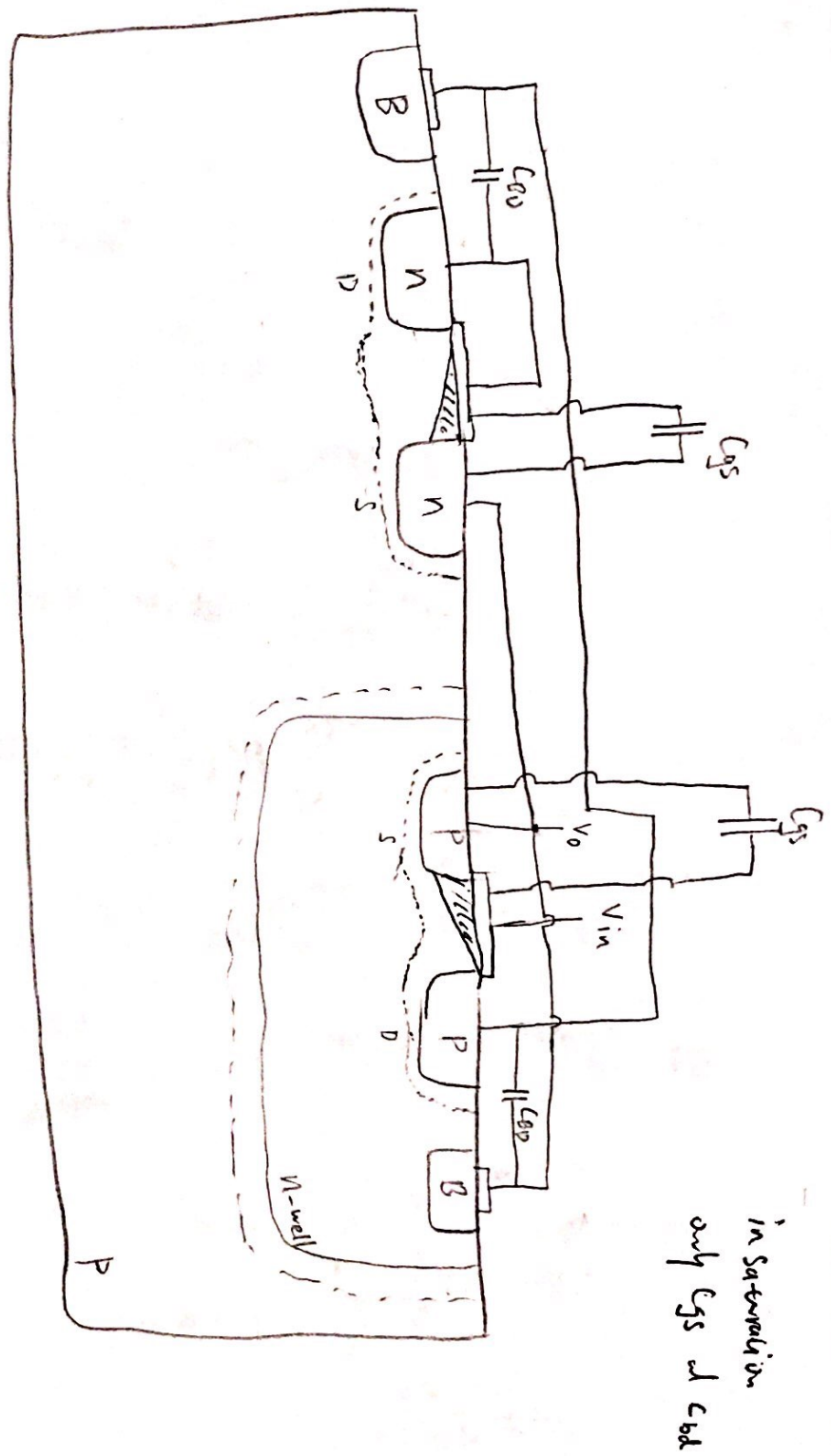
$$V_{GS} - V_{thn} + A = 0$$

$$V_o = 4 - A$$

$V_o$  decrease



Name:



Extra credit:

$$(a) \quad V_o = \frac{5 + V_{in}}{2}$$

$$g = \frac{dV_o}{dV_{in}} = \begin{cases} \frac{1}{2} & V_{in} < 3 \quad (\text{max}) \\ 0 & \text{else} \end{cases}$$

$$(b) \quad I_{dtr} = C_L dV_o$$

~~4.25~~

$$4 - 1.5 \times 10\% = 3.85$$

$$2.5 + 1.5 \times 10\% = 2.65$$

$$t_r = \cancel{C_L \int_{2.5}^{4.25} dV_o} \quad C_L \int_{2.65}^{3.85} \frac{dV_o}{I(V_o)}$$

$$= C_L \int_{2.65}^{3.85} k_n \left( \frac{W}{L} \right) \frac{1}{2} (V_{gs} - V_{th})^2 dV_o$$

$$= C_L \int_{2.65}^{3.85} 10 \times 10^{-6} \times (5 - 1 - V_o)^2 dV_o$$

$$= 5.93 \times 10^{-5} C_L$$